NSN 5962-01-215-3356

Memory Microcircuit - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5962-01-215-3356
Body Length:
Between 0.880 inches and 0.900 inches
Body Width:
Between 0.285 inches and 0.300 inches
Body Height:
Between 0.145 inches and 0.170 inches
Operating Tempurature Range:
-55.0 to 125.0 degrees celsius
Storage Tempurature Range:
-65.0 to 150.0 degrees celsius
Features Provided:
Schottky and programmable and high speed and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level output
Memory Device Type:
Rom
Test Data Document:
49956-1067465 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: